NSN 5962-01-043-7919

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Between 0.770 inches and 0.810 inches

Body Width:

Between 0.278 inches and 0.300 inches

Body Height:

Between 0.090 inches and 0.135 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Countermeasures set type an/tlq-17a

Features Provided:

Hermetically sealed and monolithic and positive outputs and schottky and high speed and w/enable and programmable and w/decoded output and 3-state output and w/storage

Inclosure Material:

Ceramic and metal

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Gold

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Precious Material And Location:

Terminals gold and body gold

Precious Material:

Gold

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

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